

NC7SZ04

TinyLogic UHS Inverter

Description

The NC7SZ04 is a single inverter from ON Semiconductor's Ultra-High Speed (UHS) series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and output are high-impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V, independent of V_{CC} operating voltage.

Features

- Ultra-High Speed: t_{PD} 2.4 ns (Typical) into 50 pF at 5 V V_{CC}
- High Output Drive: ± 24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches Performance of LCX when Operated at 3.3 V V_{CC}
- Power Down High-Impedance Inputs / Outputs
- Over-Voltage Tolerance Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry
- Ultra-Small MicroPak™ Packages
- Space-Saving SC-74A and SC70 Packages
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

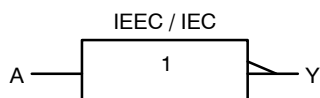


Figure 1. Logic Symbol



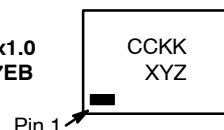
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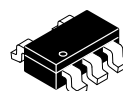
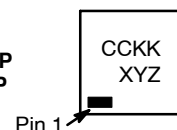
MARKING DIAGRAMS



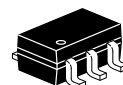
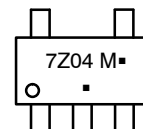
SIP6 1.45x1.0
CASE 127EB



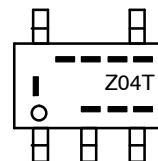
UDFN6
1.0X1.0, 0.35P
CASE 517DP



SC-74A
CASE 318BQ



SC-88A
(SC-70 5 Lead),
1.25x2
CASE 419AC-01



CC, 7Z04, Z04 = Specific Device Code
KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
M = Data Code
T = Die Run Code
--- = Year Coding Scheme
I- = Plant Code Identifier
--- = Eight-Week Datacoding Scheme

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

NC7SZ04

Pin Configurations

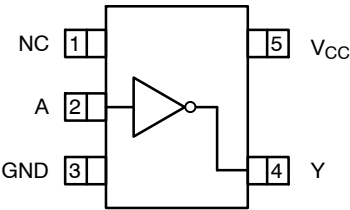


Figure 2. SC70 and SC-74A (Top View)

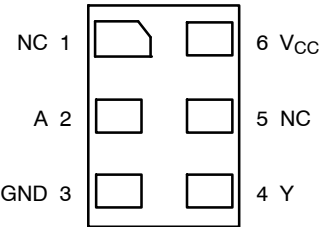


Figure 3. MicroPak (Top Through View)

PIN DEFINITIONS

Pin # SC70 / SC74 A	Pin # MicroPak	Name	Description
1	1, 5	NC	No Connect
2	2	A	Input
3	3	GND	Ground
4	4	Y	Output
5	6	V _{CC}	Supply Voltage

FUNCTION TABLE (Y = /A)

Input	Output
A	Y
L	H
H	L

H = HIGH Logic Level
L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage		−0.5	6.0	V
V _{IN}	DC Input Voltage		−0.5	6.0	V
V _{OUT}	DC Output Voltage		−0.5	6.0	V
I _{IK}	DC Input Diode Current	V _{IN} < −0.5 V	−	−50	mA
		V _{IN} > 6.0 V	−	+20	
I _{OK}	DC Output Diode Current	V _{OUT} < −0.5 V	−	−50	mA
		V _{OUT} > 6 V, V _{CC} = GND	−	+20	
I _{OUT}	DC Output Current		−	±50	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current		−	±50	mA
T _{STG}	Storage Temperature Range		−65	+150	°C
T _J	Junction Temperature Under Bias		−	+150	°C
T _L	Junction Lead Temperature (Soldering, 10 Seconds)		−	+260	°C
P _D	Power Dissipation in Still Air	SC−74A	−	225	mW
		SC70−5	−	190	
		MicroPak−6	−	327	
		MicroPak2™−6	−	327	
ESD	Human Body Model, JEDEC: JESD22−A114		−	4000	V
	Charge Device Model, JEDEC: JESD22−C101		−	2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage Operating		1.65	5.50	V
	Supply Voltage Data Retention		1.5	5.5	
V _{IN}	Input Voltage		0	5.5	V
V _{OUT}	Output Voltage		0	V _{CC}	V
T _A	Operating Temperature		−40	+85	°C
t _r , t _f	Input Rise and Fall Times	V _{CC} at 1.8 V, 2.5 V ±0.2 V	0	20	ns/V
		V _{CC} at 3.3 V ±0.3 V	0	10	
		V _{CC} at 5.0 V ±0.5 V	0	5	
θ _{JA}	Thermal Resistance	SC−74A	−	555	°C/W
		SC70−5	−	659	
		MicroPak−6	−	382	
		MicroPak2−6	−	382	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. Unused inputs must be held HIGH or LOW. They may not float.

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = 25°C			T _A = -40 to 85°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	HIGH Level Input Voltage	1.65 to 1.95		0.65 V _{CC}	–	–	0.65 V _{CC}	–	V
		2.30 to 5.50		0.70 V _{CC}	–	–	0.70 V _{CC}	–	
V _{IL}	LOW Level Input Voltage	1.65 to 1.95		–	–	0.35 V _{CC}	–	0.35 V _{CC}	V
		2.30 to 5.50		–	–	0.30 V _{CC}	–	0.30 V _{CC}	
V _{OH}	HIGH Level Output Voltage	1.65	V _{IN} = V _{IL} , I _{OH} = –100 µA	1.55	1.65	–	–	–	V
		1.80		1.70	1.80	–	1.70	–	
		2.30		2.20	2.30	–	2.20	–	
		3.00		2.90	3.00	–	2.90	–	
		4.50		4.40	4.50	–	4.40	–	
		1.65	I _{OH} = –4 mA	1.29	1.52	–	1.29	–	
		2.30	I _{OH} = –8 mA	1.90	2.15	–	1.90	–	
		3.00	I _{OH} = –16 mA	2.40	2.80	–	2.40	–	
		3.00	I _{OH} = –24 mA	2.30	2.68	–	2.30	–	
		4.50	I _{OH} = –32 mA	3.80	4.20	–	3.80	–	
V _{OL}	LOW Level Output Voltage	1.65	V _{IN} = V _{IH} , I _{OL} = 100 µA	–	0.00	0.10	–	0.10	V
		1.80		–	0.00	0.10	–	0.10	
		2.30		–	0.00	0.10	–	0.10	
		3.00		–	0.00	0.10	–	0.10	
		4.50		–	0.00	0.10	–	0.10	
		1.65	I _{OL} = 4 mA	–	0.80	0.24	–	0.24	
		2.30	I _{OL} = 8 mA	–	0.10	0.30	–	0.30	
		3.00	I _{OL} = 16 mA	–	0.15	0.40	–	0.40	
		3.00	I _{OL} = 24 mA	–	0.22	0.55	–	0.55	
		4.50	I _{OL} = 32 mA	–	0.22	0.55	–	0.55	
I _{IN}	Input Leakage Current	1.65 to 5.5	0 ≤ V _{IN} ≤ 5.5 V	–	–	±1	–	±10	µA
I _{OFF}	Power Off Leakage Current	0	V _{IN} or V _{OUT} = 5.5 V	–	–	1	–	10	µA
I _{CC}	Quiescent Supply Current	1.65 to 5.50	V _{IN} = 5.5 V, GND	–	–	2.0	–	20	µA

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	V _{CC} (V)	Conditions	T _A = +25°C			T _A = -40 to +85°C		Unit
				Min	Typ	Max	Min	Max	
t _{PLH} , t _{PHL}	Propagation Delay (Figure 4, 5)	1.65	C _L = 15 pF, R _L = 1 MΩ	–	5.3	11.4	–	12.0	ns
		1.80		–	4.4	9.5	–	10.0	
		2.50 ±0.20		–	2.9	6.5	–	7.0	
		3.30 ±0.30	C _L = 50 pF, R _L = 500 Ω	–	2.1	4.5	–	4.7	
		5.00 ±0.50		–	1.8	3.9	–	4.1	
		3.30 ±0.30		–	2.9	5.0	–	5.2	
		5.00 ±0.50		–	2.4	4.3	–	4.5	
C _{IN}	Input Capacitance	0.00		–	4	–	–	–	pF
C _{PD}	Power Dissipation Capacitance (Note 2) (Figure 6)	3.30		–	20	–	–	–	pF
		5.00		–	26	–	–	–	

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. C_{PD} is related to I_{CCD} dynamic operating current by the expression:
 $I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCstatic})$.

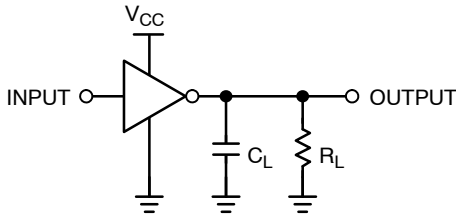


Figure 4. AC Test Circuit

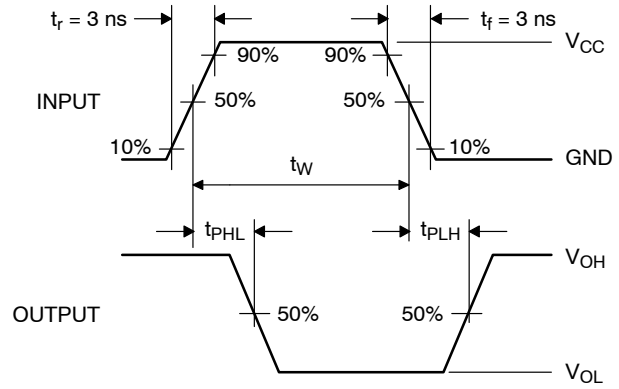
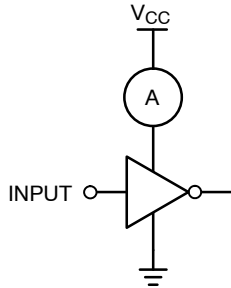


Figure 5. AC Waveforms



NOTE:

3. Input = AC Waveform; t_r = t_f = 1.8 ns;
 PRR = 10 MHz; Duty Cycle = 50%.

Figure 6. I_{CCD} Test Circuit

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DEVICE ORDERING INFORMATION

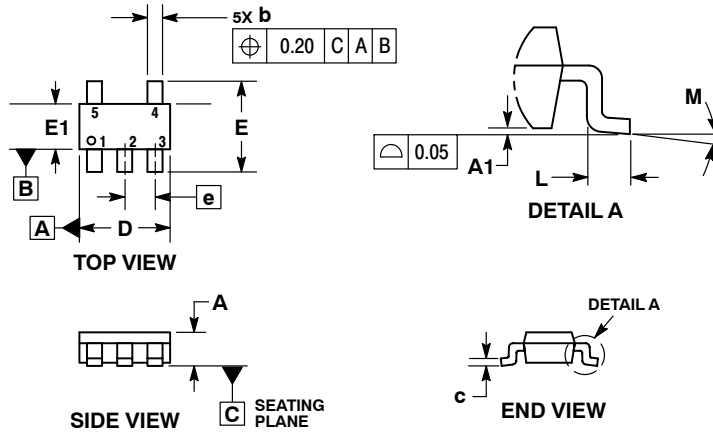
Device	Top Mark	Packages	Shipping [†]
NC7SZ04M5X	7Z04	5-Lead SC-74A, 1.6mm	3000 / Tape & Reel
NC7SZ04P5X	Z04	5-Lead SC70, EIAJ SC-88a, 1.25 mm Wide	3000 / Tape & Reel
NC7SZ04L6X	CC	6-Lead MicroPak, 1.00 mm Wide	5000 / Tape & Reel
NC7SZ04FHX	CC	6-Lead, MicroPak2, 1 x 1 mm Body, .35 mm Pitch	5000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

SC-74A
CASE 318BQ
ISSUE B

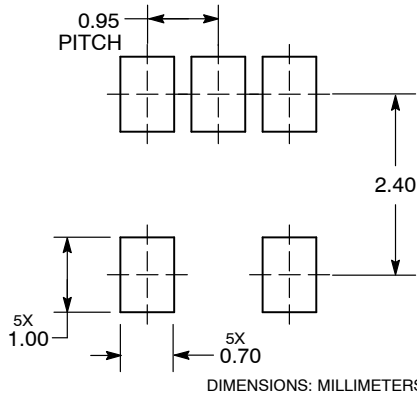


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DIM	MILLIMETERS	
	MIN	MAX
A	0.90	1.10
A1	0.01	0.10
b	0.25	0.50
c	0.10	0.26
D	2.85	3.15
E	2.50	3.00
E1	1.35	1.65
e	0.95 BSC	
L	0.20	0.60
M	0°	10°

RECOMMENDED SOLDERING FOOTPRINT*



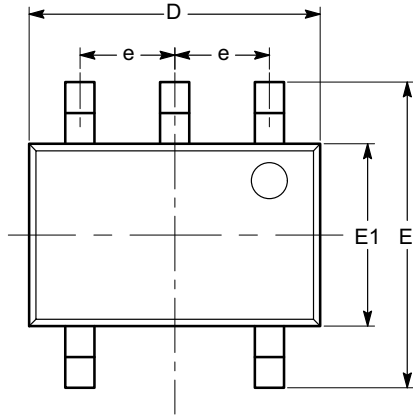
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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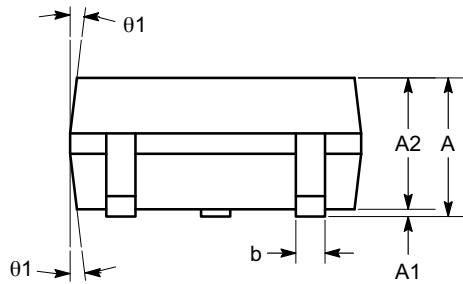
PACKAGE DIMENSIONS

SC-88A (SC-70 5 Lead), 1.25x2
CASE 419AC-01
ISSUE A

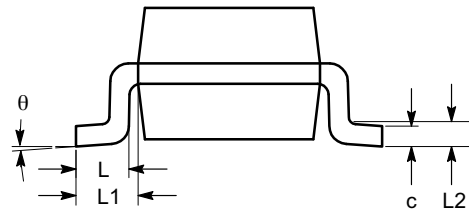


TOP VIEW

SYMBOL	MIN	NOM	MAX
A	0.80		1.10
A1	0.00		0.10
A2	0.80		1.00
b	0.15		0.30
c	0.10		0.18
D	1.80	2.00	2.20
E	1.80	2.10	2.40
E1	1.15	1.25	1.35
e	0.65 BSC		
L	0.26	0.36	0.46
L1	0.42 REF		
L2	0.15 BSC		
θ	0°		8°
$\theta 1$	4°		10°



SIDE VIEW



END VIEW

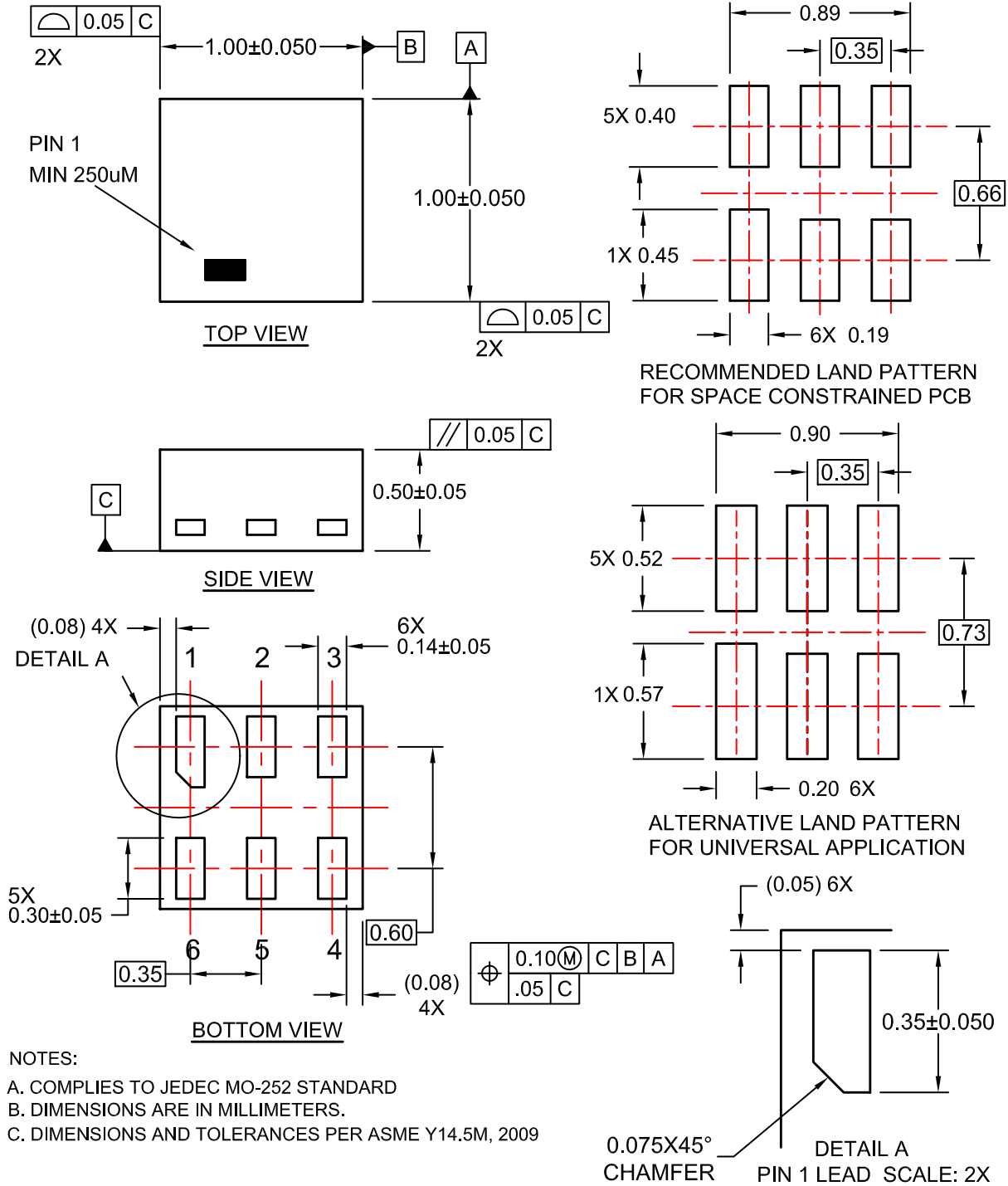
Notes:

- (1) All dimensions are in millimeters. Angles in degrees.
- (2) Complies with JEDEC MO-203.

NC7SZ04

PACKAGE DIMENSIONS

UDFN6 1.0X1.0, 0.35P
CASE 517DP
ISSUE O



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